



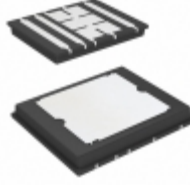
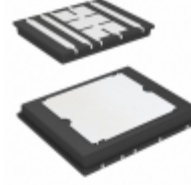
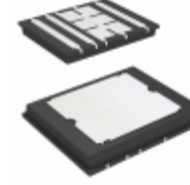
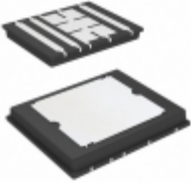
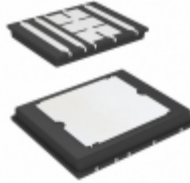
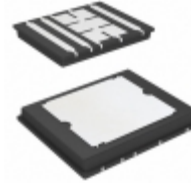
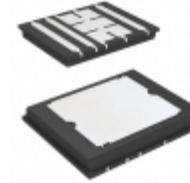
	<p><b>SIE860DF-T1-GE3</b></p> <p><b>Hersteller-Teilenummer:</b> <a href="#">SIE860DF-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 60A POLARPAK</p> <p><b>Datenblätter:</b>  <a href="#">SIE860DF-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SIE860DF-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N-CH 30V 60A POLARPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	<a href="#">Require For Quote &amp; Check Stock</a>
VGS (th) (Max) @ Id	2.5V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	10-PolarPAK® (M)
Serie	TrenchFET®
Rds On (Max) @ Id, Vgs	2.1 mOhm @ 21.7A, 10V
Verlustleistung (max)	5.2W (Ta), 104W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	10-PolarPAK® (M)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	4500pF @ 15V
Gate Charge (Qg) (Max) @ Vgs	105nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)

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### Sie können auch interessiert

<p>sein:</p>  <p><b>SIE864DF-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 45A POLARPAK</p>	 <p><b>SIE860DF-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>	 <p><b>SIE854DF-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 100V 60A POLARPAK</p>	 <p><b>SIE862DF-T1-GE3</b> Vishay Siliconix MOSFET N-CH 30V 50A POLARPAK</p>
 <p><b>SIE860DF-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>	 <p><b>SIE860DF-T1-E3</b> Vishay Siliconix MOSFET N-CH 30V 60A POLARPAK</p>	 <p><b>SIE854DF-T1-GE3</b> Vishay Siliconix MOSFET N-CH 100V 60A POLARPAK</p>	 <p><b>SIE862DF-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 50A POLARPAK</p>

### Verwandtes Hot-Keyword

Mehr

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